

The CD54HCT161 is obsolete and no longer is supplied.

CD54/74HC161, CD54/74HCT161, CD54/74HC163, CD54/74HC163

Data sheet acquired from Harris Semiconductor SCHS154D High-Spee

February 1998 - Revised October 2003

High-Speed CMOS Logic Presettable Counters

Features

- 'HC161, 'HCT161 4-Bit Binary Counter, Asynchronous Reset
- 'HC163, 'HCT163 4-Bit Binary Counter, Synchronous Reset
- · Synchronous Counting and Loading
- Two Count Enable Inputs for n-Bit Cascading
- · Look-Ahead Carry for High-Speed Counting
- Fanout (Over Temperature Range)
 - Standard Outputs............ 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \leq 1 \mu \text{A}$ at $V_{\mbox{\scriptsize OL}}, \, V_{\mbox{\scriptsize OH}}$

Description

The 'HC161, 'HCT161, 'HC163, and 'HCT163 are presettable synchronous counters that feature look-ahead carry logic for use in high-speed counting applications. The 'HC161 and 'HCT161 are asynchronous reset decade and binary counters, respectively; the 'HC163 and 'HCT163 devices are decade and binary counters, respectively, that are reset synchronously with the clock. Counting and parallel presetting are both accomplished synchronously with the negative-to-positive transition of the clock.

A low level on the synchronous parallel enable input, SPE, disables counting operation and allows data at the P0 to P3 inputs to be loaded into the counter (provided that the setup and hold requirements for SPE are met).

All counters are reset with a low level on the Master Reset input, MR. In the 'HC163 and 'HCT163 counters (synchronous reset types), the requirements for setup and hold time with respect to the clock must be met.

Two count enables, PE and TE, in each counter are provided for n-bit cascading. In all counters reset action occurs regardless of the level of the $\overline{\text{SPE}}$, PE and TE inputs (and the clock input, CP, in the 'HC161 and 'HCT161 types).

If a decade counter is preset to an illegal state or assumes an illegal state when power is applied, it will return to the normal sequence in one count as shown in state diagram.

The look-ahead carry feature simplifies serial cascading of the counters. Both count enable inputs (PE and TE) must be high to count. The TE input is gated with the Q outputs of all four stages so that at the maximum count the terminal count (TC) output goes high for one clock period. This TC pulse is used to enable the next cascaded stage.

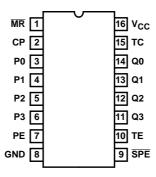
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC161F3A	-55 to 125	16 Ld CERDIP
CD54HC163F3A	-55 to 125	16 Ld CERDIP
CD54HCT163F3A	-55 to 125	16 Ld CERDIP
CD74HC161E	-55 to 125	16 Ld PDIP
CD74HC161M	-55 to 125	16 Ld SOIC
CD74HC161MT	-55 to 125	16 Ld SOIC
CD74HC161M96	-55 to 125	16 Ld SOIC
CD74HC163E	-55 to 125	16 Ld PDIP
CD74HC163M	-55 to 125	16 Ld SOIC
CD74HC163MT	-55 to 125	16 Ld SOIC
CD74HC163M96	-55 to 125	16 Ld SOIC
CD74HCT161E	-55 to 125	16 Ld PDIP
CD74HCT161M	-55 to 125	16 Ld SOIC
CD74HCT161MT	-55 to 125	16 Ld SOIC
CD74HCT161M96	-55 to 125	16 Ld SOIC
CD74HCT163E	-55 to 125	16 Ld PDIP
CD74HCT163M	-55 to 125	16 Ld SOIC
CD74HCT163MT	-55 to 125	16 Ld SOIC
CD74HCT163M96	-55 to 125	16 Ld SOIC

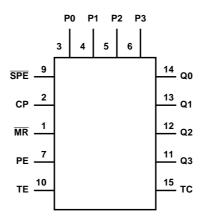
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD54HC161, CD54HCT161, CD54HC163, CD54HCT163 (CERDIP) CD74HC161, CD74HCT161, CD74HC163, CD74HCT163 (PDIP, SOIC) TOP VIEW



Functional Diagram



MODE SELECT - FUNCTION TABLE FOR 'HC161 AND 'HCT161

			INP	UTS			OUTPUTS		
OPERATING MODE	MR	СР	PE	TE	SPE	P _n	Q _n	TC	
Reset (Clear)	L	Х	Х	Х	Х	Х	L	L	
Parallel Load	Н	1	Х	Х	I	I	L	L	
	Н	1	Х	Х	I	h	Н	(Note 1)	
Count	Н	1	h	h	h (Note 3)	Х	Count	(Note 1)	
Inhibit	Н	Х	I (Note 2)	Х	h (Note 3)	Х	q _n	(Note 1)	
	Н	Х	Х	I (Note 2)	h (Note 3)	Х	q _n	L	

MODE SELECT - FUNCTION TABLE FOR 'HC163 AND 'HCT163

			INP	UTS			OUTPUTS		
OPERATING MODE	MR	СР	PE	TE	SPE	P _n	Q _n	TC	
Reset (Clear)	I	1	Х	Х	Х	Х	L	L	
Parallel Load	h (Note 3)	1	Х	Х	I	I	L	L	
	h (Note 3)	1	Х	Х	I	h	Н	(Note 1)	
Count	h (Note 3)	1	h	h	h (Note 3)	Х	Count	(Note 1)	
Inhibit	h (Note 3)	Х	I (Note 2)	Х	h (Note 3)	Х	q _n	(Note 1)	
	h (Note 3)	Х	Х	I (Note 2)	h (Note 3)	Х	q _n	L	

 $H = High \ voltage \ level \ steady \ state; \ L = Low \ voltage \ level \ steady \ state; \ h = High \ voltage \ level \ one \ setup \ time \ prior \ to \ the \ Low-to-High \ clock \ transition; \ X = Don't \ Care; \ q = Lower \ case \ letters \ indicate \ the \ state \ of \ the \ referenced \ output \ prior \ to \ the \ Low-to-High \ clock \ transition.$ NOTES:

- 1. The TC output is High when TE is High and the counter is at Terminal Count (HHHH for HC/HCT161 and 'HC/HCT163).
- 2. The High-to-Low transition of PE or TE on the 'HC/HCT161 and the 'HC/HCT163 should only occur while CP is HIGH for conventional operation.
- 3. The Low-to-High transition of $\overline{\text{SPE}}$ on the 'HC/HCT161 and $\overline{\text{SPE}}$ or $\overline{\text{MR}}$ on the 'HC/HCT163 should only occur while CP is HIGH for conventional operation.

Absolute Maximum Ratings DC Supply Voltage, V_{CC} -0.5V to 7V DC Input Diode Current, I_{IK}

DC Output Diode Current, I_{OK} DC Drain Current, per Output, IO

DC Output Source or Sink Current per Output Pin, IO

Operating Conditions

Temperature Range, T _A 55 ^o C to 125 ^o 0
Supply Voltage Range, V _{CC}
HC Types2V to 6\
HCT Types
DC Input or Output Voltage, $V_I,V_O\dots\dots\dots\dots$ 0V to V_{CO}
Input Rise and Fall Time
2V 1000ns (Max
4.5V 500ns (Max
6V

Thermal Information

Thermal Resistance (Typical, Note 4)	θ_{JA} (°C/W)
E (PDIP) Package	67
M (SOIC) Package	73
Maximum Junction Temperature	150 ^o C
Maximum Storage Temperature Range65 ⁶	C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

4. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TEST CONDITIONS		v _{cc}		25°C		-40°C 1	TO 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(S)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES					-	-			-			-
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	٧
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	٧
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	Voн	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
OWOO LOAGS			-0.02	6	5.9	-	-	5.9	-	5.9	-	٧
High Level Output	7		-	-	-	-	-	-	-	-	-	٧
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	٧
TTE LOAGS			-5.2	6	5.48	-	-	5.34	-	5.2	-	٧
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	٧
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	٧
CIVIOO LOAGS			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	7		-	-	-	-	-	-	-	-	-	٧
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
TTL LUaus			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА

DC Electrical Specifications (Continued)

		TES CONDI		V _{CC}		25°C		-40°C 1	O 85°C	-55 ⁰ C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ
HCT TYPES							•				•	
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I _I	V _{CC} and GND	0	5.5	-		±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 5)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

NOTE:

5. For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
P0 - P3	0.25
PE	0.65
СР	1.05
MR	0.8
SPE	0.5
TE	1.05

NOTE: Unit Load is $\Delta I_{\hbox{\footnotesize CC}}$ limit specified in DC Electrical Table, e.g., 360µA max at 25°C.

Prerequisite For Switching Specifications

		TEST	v _{cc}		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Maximum CP Frequency	f _{MAX}	-	2	6	-	-	5	-	4	-	MHz
(Note 6)			4.5	30	-	-	24	-	20	-	MHz
			6	35	-	-	28	-	24	-	MHz
CP Width (Low)	t _{W(L)}	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
MR Pulse Width (161)	t _W	-	2	100	-	-	125	-	150	-	ns
			4.5	20	-	-	25	-	30	-	ns
			6	17	-	-	21	-	26	-	ns
Setup Time, Pn to CP	t _{SU}	-	2	60	-	-	75	-	90	-	ns
			4.5	12	-	-	15	-	18	-	ns
			6	10	-	-	13	-	15	-	ns
Setup Time, PE or TE to CP	t _{SU}	-	2	50	-	-	65	-	75	-	ns
			4.5	10	-	-	13	-	15	-	ns
			6	9	-	-	11	-	13	-	ns
Setup Time, SPE to CP	t _{SU}	-	2	60	-	-	75	-	90	-	ns
			4.5	12	-	-	15	-	18	-	ns
			6	10	-	-	13	-	15	-	ns
Setup Time, MR to CP (163)	t _{SU}	-	2	65	-	-	80	-	100	-	ns
			4.5	13	-	-	16	-	20	-	ns
			6	11	-	-	14	-	17	-	ns
Hold Time, PN to CP	t _H	-	2	3	-	-	3	-	3	-	ns
			4.5	3	-	-	3	-	3	-	ns
			6	3	-	-	3	-	3	-	ns
Hold Time, TE or PE to CP	t _H	-	2	0	-	-	0	-	0	-	ns
			4.5	0	-	-	0	-	0	-	ns
			6	0	-	-	0	-	0	-	ns
Hold Time, SPE to CP	t _H	-	2	0	-	-	0	-	0	-	ns
			4.5	0	-	-	0	-	0	-	ns
			6	0	-	-	0	-	0	-	ns
Recovery Time, MR to CP (161)	t _{REC}	-	2	75	-	-	95	-	110	-	ns
			4.5	15	-	-	19	-	22	-	ns
			6	13	-	-	16	-	19	-	ns

Prerequisite For Switching Specifications (Continued)

		TEST	v _{cc}		25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES									_		
Maximum CP Frequency	f _{MAX}	-	4.5	30	-	-	24	-	20	-	MHz
CP Width (Low) (Note 6)	t _{W(L)}	-	4.5	16	-	-	20	-	24	-	ns
MR Pulse Width (161)	t _W	-	4.5	20	-	-	25	-	30	-	ns
Setup Time, Pn to CP	tsu	-	4.5	10	-	-	13	-	15	-	ns
Setup Time, PE or TE to CP	t _{SU}	-	4.5	13	-	-	16	-	20	-	ns
Setup Time, SPE to CP	t _{SU}	-	4.5	12	-	-	15	-	18	-	ns
Setup Time, MR to CP (163)	tsu	-	4.5	13	-	-	16	-	20	-	ns
Hold Time, PN to CP	t _H	-	4.5	5	-	-	5	-	5	-	ns
Hold Time, TE or PE to CP	t _H	-	4.5	3	-	-	3	-	3	-	ns
Hold Time, SPE to CP	t _H	-	4.5	3	-	-	3	-	3	-	ns
Recovery Time, MR to CP (161)	^t REC	-	4.5	15	-	-	19	-	22	-	ns

NOTE:

6. Applies to non-cascaded operation only. With cascaded counters clock to terminal count propagation delays, count enables (PE or TE)-to-clock setup times, and count enables (PE or TE)-to-clock hold times determine maximum clock frequency. For example with these HC devices:

$$f_{MAX} \text{ (CP)} = \frac{1}{\text{CP-to-TC prop. delay} + \text{TE-to-CP setup} + \text{TE-to-CP Hold}} = \frac{1}{37 + 10 + 0} \approx 21 \text{MHz} \text{ (min)}$$

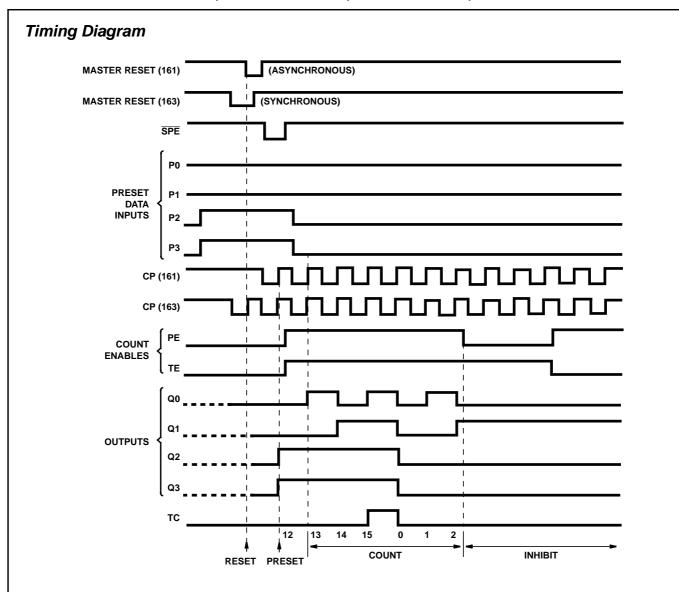
Switching Specifications $C_L = 50 pF$, Input t_r , $t_f = 6 ns$

		TEST		25°C				С ТО °С	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES								-		-	
Propagation Delay	t _{PHL} , t _{PLH}	$C_L = 50pF$									
CP to TC			2	-	-	185	-	230	-	280	ns
			4.5	-	-	37	-	46	-	56	ns
		C _L = 15pF	5	-	15	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	31	-	39	-	48	ns
CP to Qn	t _{PHL} , t _{PLH}	C _L = 50pF	2	-	-	185	-	230	-	280	ns
			4.5	-	-	37	-	46	-	56	ns
		C _L = 15pF	5	-	15	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	31	-	39	-	48	ns
TE to TC	t _{PHL} , t _{PLH}	C _L = 50pF	2	-	-	120	-	150	-	180	ns
			4.5	-	-	24	-	30	-	36	ns
		C _L = 15pF	5	-	9	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	20	-	26	-	31	ns

Switching Specifications $C_L = 50 pF$, Input t_r , $t_f = 6 ns$ (Continued)

		TEST			25°C			С ТО °С		C TO 5°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
MR to Qn (161)	t _{PHL}	C _L = 50pF	2	-	-	210	-	265	-	315	ns
			4.5	-	-	42	-	53	-	63	ns
		C _L = 15pF	5	-	18	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	36	-	45	-	54	ns
MR to TC (161)	t _{PHL}	C _L = 50pF	2	-	-	210	-	265	-	315	ns
			4.5	-	-	42	-	53	-	63	ns
		C _L = 50pF	6	-	-	36	-	45	-	54	ns
Output Transition Time	t _{THL} , t _{TLH}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Power Dissipation Capacitance (Notes 7, 8)	C _{PD}	-	5	-	60	-	-	-	-	-	pF
Input Capacitance	C _{IN}	C _L = 50pF	-	10	-	10	-	10	-	10	pF
HCT TYPES										•	•
Propagation Delay											
CP to TC	t _{PHL} , t _{PLH}	C _L = 50pF	4.5	-	-	42	-	53	-	63	ns
		C _L = 15pF	5	-	18	-	-	-	-	-	ns
CP to Qn	t _{PHL} , t _{PLH}	C _L = 50pF	4.5	-	-	39	-	49	-	59	ns
		C _L = 15pF	5	1	16	-	1	-	-	-	ns
TE to TC	t _{PHL} , t _{PLH}	C _L = 50pF	4.5	ı	-	32	1	40	-	48	ns
		C _L = 15pF	5	-	13	-	-	-	-	-	ns
MR to Qn (161)	t _{PHL}	C _L = 50pF	4.5	-	-	50	-	63	-	75	ns
		C _L = 15pF	5	-	21	-	-	-	-	-	ns
MR to TC (161)	t _{PHL}	C _L = 50pF	4.5	-	-	50	-	63	-	75	ns
Output Transition Time	t _{THL} , t _{TLH}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Power Dissipation Capacitance (Notes 7, 8)	C _{PD}	-	5	-	63	-	-	-	-	-	pF
Input Capacitance	C _{IN}	C _L = 50pF	-	10	-	10	-	10	-	10	pF

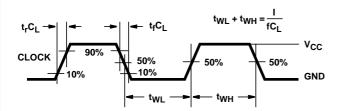
C_{PD} is used to determine the dynamic power consumption, per package.
 P_D = C_{PD} V_{CC}² f_i + Σ(C_L V_{CC}² f_O) where f_i = Input Frequency, f_O = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.



Sequence illustrated on waveforms:

- 1. Reset outputs to zero.
- 2. Preset to binary twelve.
- 3. Count to thirteen, fourteen, fifteen, zero, one, and two.
- 4. Inhibit.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V $_{\rm CC}$ to 90% V $_{\rm CC}$ in accordance with device truth table. For f $_{\rm MAX}$, input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

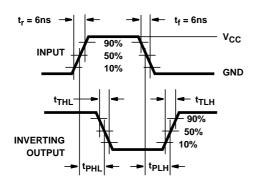


FIGURE 3. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

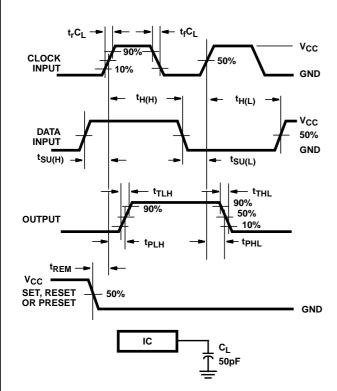
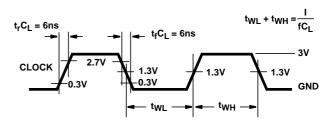


FIGURE 5. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS



NOTE: Outputs should be switching from 10% V $_{CC}$ to 90% V $_{CC}$ in accordance with device truth table. For f $_{MAX}$, input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

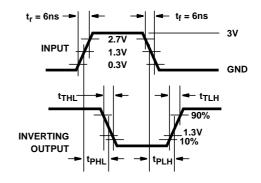


FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

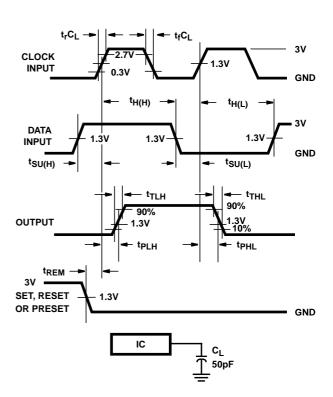


FIGURE 6. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS





9-Oct-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
CD54HC161F	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC161F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC163F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT161F3A	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
CD54HCT163F	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT163F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC161E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC161EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC161M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC161M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC161M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC161M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC161ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC161MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC161MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC161MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC161MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC163E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC163EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC163M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC163M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC163M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC163M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC163ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC163MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC163MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC163MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



PACKAGE OPTION ADDENDUM

9-Oct-2007

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³
CD74HC163MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT161E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT161EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT161M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT161M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT161M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT161M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT161ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT161MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT161MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT161MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT161MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT163E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT163EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT163M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT163M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT163M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT163M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT163ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT163MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT163MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT163MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLII
CD74HCT163MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.



PACKAGE OPTION ADDENDUM

9-Oct-2007

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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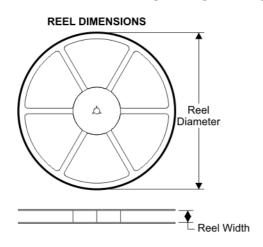
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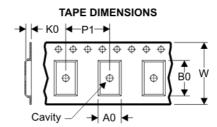


PACKAGE MATERIALS INFORMATION

12-Feb-2008

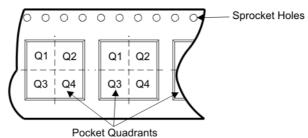
TAPE AND REEL BOX INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

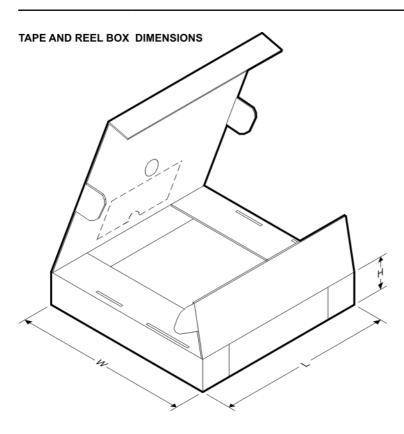


Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC161M96	D	16	SITE 27	330	16	6.5	10.3	2.1	8	16	Q1
CD74HC163M96	D	16	SITE 27	330	16	6.5	10.3	2.1	8	16	Q1
CD74HCT161M96	D	16	SITE 27	330	16	6.5	10.3	2.1	8	16	Q1
CD74HCT163M96	D	16	SITE 27	330	16	6.5	10.3	2.1	8	16	Q1

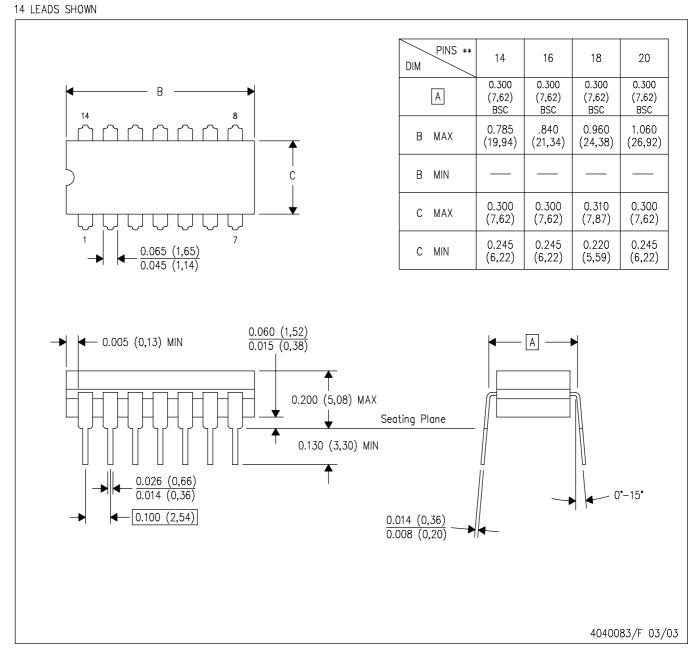




12-Feb-2008



Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
CD74HC161M96	D	16	SITE 27	342.9	345.9	28.58
CD74HC163M96	D	16	SITE 27	342.9	345.9	28.58
CD74HCT161M96	D	16	SITE 27	342.9	345.9	28.58
CD74HCT163M96	D	16	SITE 27	342.9	345.9	28.58

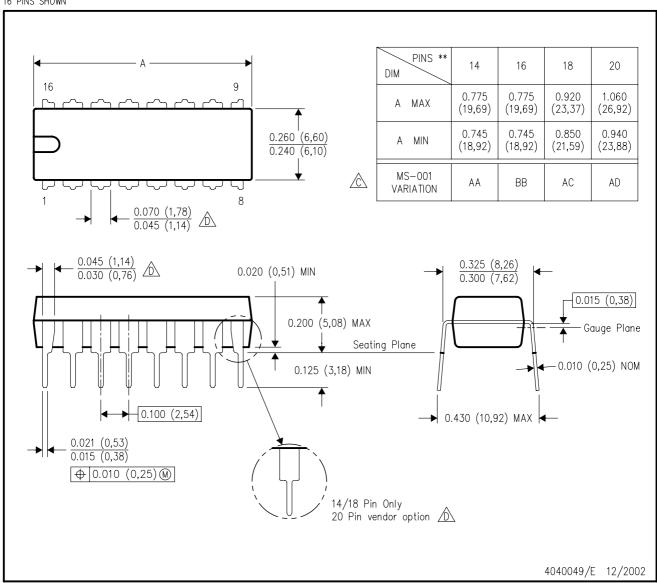


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

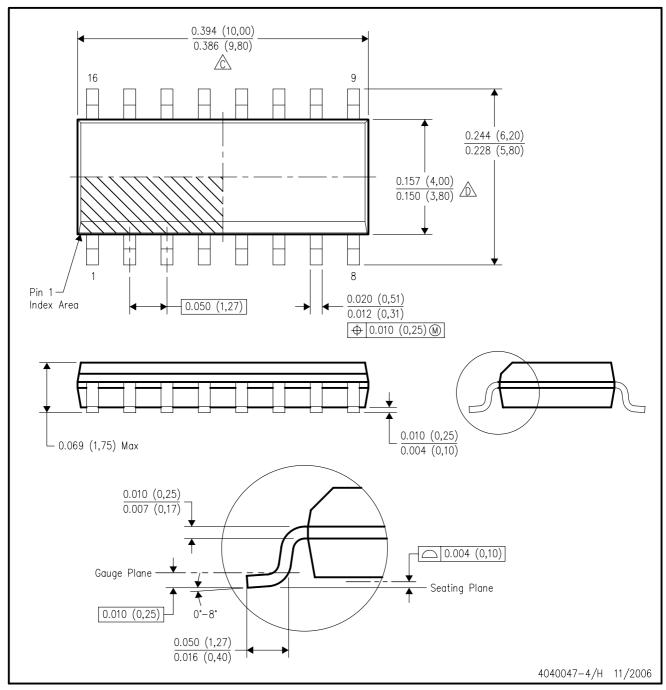
16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.

D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.

 E. Reference JEDEC MS-012 variation AC.



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